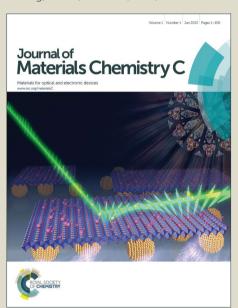


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Hole Mobility of $3.56~\text{cm}^2\text{V}^{-1}\text{s}^{-1}$ Accomplished Using More Extended Dithienothiophene with Furan Flanked Diketopyrrolopyrrole Polymer

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Highly extended dithienothiophene comonomoer building block was used in combination with highly fused aromatic furan substituted diketopyrrolopyrrole for the synthesis of novel donor
10 acceptor alternating copolymer PDPPF-DTT. Upon testing PDPPF-DTT as a channel semiconductor in top contact bottom gate organic field effect transistors (OFETs), it exhibits p-channel behaviour. The highest hole mobility of 3.56 cm²/vs was reported for PDPPF-DTT. To our knowledge, this is the highest mobility reported so far for the furan flanked diketopyrrolopyrrole class of copolymers using conventional device geometry with straightforward processing.

Introduction

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Since last decade, there are several reports on high performance 20 polymeric semiconductors for the p-channel and n-channel organic field effect transistors (OFETs). 1-4 Since last few years, a significant progress has been made towards the development of a solution processable high mobility organic semiconducting polymeric materials. ¹⁻⁴ Nowadays achieving mobility higher than 25 0.1 cm²/Vs in organic field effect transistors (OFETs) devices become a very common trend in various worldwide labs due to exploration of new building blocks and their effective utilization for designing a new polymeric organic semiconductors. 5-7, 2 Such a high performance materials are absolutely important for making 30 flexible printed organic electronic devices for various applications ranging from complementary circuits, driver for active matrix display, sensors, and active donor materials for organic photovoltaics.⁸⁻¹¹ Among reported various polymeric structures, donor-acceptor (D-A) based alternating copolymers 35 becomes one of the most successful design regulation to achieve high performance in both OFETs and organic photovoltaics. 12-18 D-A copolymers improves the intramolecular interaction due to the orbital overlap of highest occupied molecular orbital (HOMO) of donor and the lowest unoccupied molecular orbital 40 (LUMO) of acceptor which causes widening of UV-vis-NIR absorption and reduction in band gap. Low energy charge transfer transitions and the crystallinity can be enhanced through partial polarity on the D-A moieities. 1,17,18 On the basis of ionization potential of donor and the electron affinity of acceptor 45 incorporated in the conjugated backbone, the copolymers can be classified into strong donor-strong acceptor, strong donor-weak

acceptor, weak donor-strong acceptor and weak donor-weak acceptor respectively. 19-22 In addition to that, the planarity of the fused aromatic building blocks in the conjugated backbone, interso chain interaction, donor-acceptor partially polarity determines the π-π stacking and interlayer d-spacing of the polymeric chains. 17, 18 There are numerous donor-acceptor based copolymers have been reported in the literature for high performing OFET devices but among them, most of the reported highest mobility copolymers are either made up of diketopyrrolopyrrole (DPP) 1,4,13, isoindigo (IS) or other fused aromatic conjugated building blocks in the main backbone. 25,26, 2 These all fused rings have common feature of lactam units which assist for better orbital overlapping, enhancing intermolecular interaction and inducing solution processibility due to long branched alkyl chain substitution on the nitrogen atom.

Recently, DPP based polymeric materials have attracted significant attention in the organic electronic community due to its low cost, easy synthesis, wide scope of structural 65 variation with respect to selection of heterocyclic moiety at 2, 5positions. π - π Intermolecular interactions, and optical properties of such materials can be easily tuned by using various conjugated blocks adjacent to the DPP. 1, 27 The planarity in such heterocyclic flanked DPP structures can be induced due to the substitution of 70 various heteroatoms such as sulfur, oxygen, selenium and nitrogen on thiophene/furan/selenophene/pyridine and their interaction with oxygen substituted on carbonyl group. Such a intramolecular interaction can significantly enhance the π - π interaction.^{1,28} In the literature, most of the materials are based on 75 the thiophene flanked DPP (DPPT) but there are very few reports on furan flanked DPP (DPPF) materials. 29-35 Furan is also one of the most important biological degradable green conjugated building blocks and has not explored in detail yet for synthesizing organic semiconductors. Furan can be successfully and 80 effectively utilized in combination with DPP for designing new high performance solution processable organic semiconductors. Since last few years, our group has been developing furan flanked DPP based conjugated polymers for elevating its performance in OFET devices via rational design principle. 36, 37 On the other 85 hand, linearly fused oligothiophene-based compounds derived from dithieno [3, 2-b: 2', 3'-d] thiophene (DTT) have been successfully used in a variety of organic optoelectronic devices,

Ç₁₀H₂₁ Pd₂ (dba)₃, P(o-tolyl)₃ C₁₀H₂₁ Toluene 105 °C C₁₂H₂₅ 2 C₁₀H₂₁ PDPPF-DTT Trimethyl tin chloride THE

Scheme 1 Synthesis of PDPPF-DTT via Stille coupling polymerization.

5 because the DTT unit has relatively high hole mobility due to the fused thiophene core.38-40 A fused thiophene motifs such as dithienothiophene are well known for their strong intermolecular S..S interactions and structural planarity. 41-43 The sulfur rich electron donating DTT unit exhibits structural rigidity in 10 conjugated backbone arising from its fused chemical structure, and therefore DTT building blocks in combination with furan flanked DPP may achieve higher performance in OFET devices.

In this work, we report the design and synthesis of a solution-processable p-channel polymer semiconductor PDPPF-15 DTT (Scheme 1), which showed the highest hole mobility of 3.56 cm²/Vs in top contact bottom gate OFET devices. To the best of our knowledge, this performance is one of the highest performances among all furan substituted DPP based copolymers with simple OFET device geometry. In this polymer, furan 20 flanked DPP was used as a core donor-acceptor (D-A) building block in combination with another fused aromatic electron donating dithienothiophene DTT comonomer. The combination of two aromatic fused conjugated building blocks (DPPF and DTT) in the backbone have a strong tendency to form π - π stacks 25 with a large overlapping area that is favorable for effective charge carrier transport. In addition to that, the strong electron accepting DPP moiety with furan-DTT-furan electron donating building block assist to improve the intermolecular interactions arising from D-A inter-chain interaction whereas heteroatom contact 30 induces a higher order molecular organization.

Results and Discussion

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The polymer **PDPPF-DTT** was synthesized in a straightforward manner via Stille coupling polymerization (Scheme1) using 3,6bis(5-bromofuran-2-yl)-2,5-bis(2-decyltetradecyl)pyrrolo[3,4-35 c]pyrrole-1,4(2H,5H)-dione (2) and bis(trimethylstannyl)dithieno[3,2-b:2',3'-d]thiophene (4) in 69 % vield (see Experimental procedure as well). Compounds 2 and 4 were synthesized according to the earlier published procedure.³⁸, ³¹ In order to improve the solution processibility of **PDPPF-DTT** 40 polymer, the long 2-decyl-1-tetradecyl branched alkyl chain was attached to the lactam nitrogen atom of DPPF building block.

The low molecular weight fractions and other catalytic impurities present in PDPPF-DTT polymer was successfully removed by Sohxlet extraction using methanol, acetone and hexane solvents. 45 The highest molecular weight and pure fraction of PDPPF-DTT was extracted by using chloroform solvent. The excess chloroform was removed by rotary evaporation and the viscous PDPPF-DTT polymer solution in chloroform was precipitated in excess methanol as a non-solvent. The polymer was filtered and 50 dried under vacuum for further characterization. This purified polymer is soluble in various organic solvents such as chlorobenzene, chloroform and toluene at room temperature due to the longer branched alkyl chain. The molecular weight of purified PDPPF-DTT polymer was determined by high 55 temperature gel permeation chromatography (GPC). The number average (M_n) and weight average molecular weight (M_w) are 24726 and 55035 g/mol, respectively, at a column temperature of 160 °C using trichlorobenzene as eluent. The thermal properties of PDPPF-DTT were evaluated by thermogravimetric analysis 60 (TGA) and differential scanning calorimetry (DSC) techniques, respectively. TGA showed 5% weight loss decomposition temperature at 389 °C under nitrogen (See SI). Such a high decomposition temperature clearly indicates an extremely high thermal stability of the polymer. DSC heating and cooling cycles 65 were repeated two times from room temperature till 350 °C. PDPPF-DTT exhibits an endothermic peak at 336 °C and an exothermic peak at 347 °C during the second heating-cooling cycles respectively (See SI). These peaks are related to the melting and crystallization temperatures of this polymer (see 70 Supplementary Information). Additional two exothermic peaks observed at 255 °C and 229 °C and they might be arising from the longer branched alkyl side chain transitions.

The optical properties of PDPPF-DTT in solution and thin film were characterized by UV-vis-NIR spectroscopy as shown in 75 Figure 1a. For the solution measurement, the polymer solution in chloroform was used whereas for the thin film, the thin layer of polymer was spin coated onto the glass slide. PDPPF-DTT exhibits wide UV-vis-NIR absorption starting from 350 nm to 900 nm. A strong absorption between 500 to 900 nm has been

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observed for PDPPF-DTT polymer which is in the same range compared to the other DPP based polymers. The absorption maximum (λ_{max}) has been recorded at ~782 nm in solution. For thin film, the λ_{max} is almost identical as that of solution λ_{max} and 5 only the difference is the broadness of peak in solid compared to solution. The solution and thin film optical absorption similarity might be attributed to the aggregation of PDPPF-DTT polymer in solution at room temperature even the polymer seemed to be completely dissolved. The absorption cut off for the solid UV-10 vis-NIR measurement is around 880 nm in solution whereas in the solid state, the cut off value measured around 905 nm. The optical band gap (Eg opt) was determined from the absorption cutoff of in the solid state and which has found around 1.37 eV, demonstrating that PDPPF-DTT is a small band gap 15 semiconductor. The HOMO energy level of PDPPF-DTT was calculated by photoelectron spectroscopy in air (PESA) method using a spin coated thin film of polymer on the glass substrate. The surface of PPPD-DTT polymer thin film was slowly bombarded with ultraviolet energy and then slowly polymer thin 20 film started emitting photoelectrons of certain energy level. This energy is known as photoelectron work function. The photoelectron output is plotted with horizontal X-axis as the UV energy applied and the vertical Y-axis as the standardized photoelectron yield ratio, the result is a line with a specific slope 25 of degree (Y/eV).

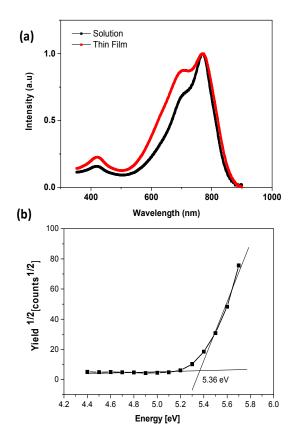
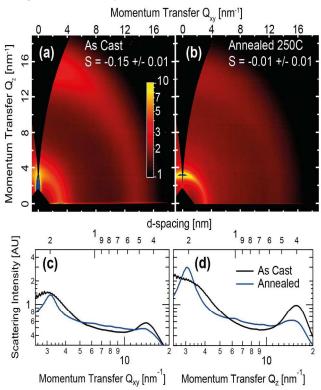


Figure 1. (a) UV-vis absorption spectra of **PDPPF-DTT** in chloroform solution and in thin film and (b) Photoelectron spectroscopy in air (PESA) analysis of **PDPPF-DTT** spin coated thin films on glass.

The HOMO value of PDPPF-DTT was calculated from the onset energy level recorded in PESA and which is shown in Figure 1b. The HOMO value for PDPPF-DTT is -5.36 eV and therefore it is expected to use this material as a good donor polymer in OFET devices. The obtained deeper HOMO is appropriate for the higher oxidation stability.

Grazing Incidence Wide Angle X-ray Scattering (GIWAXS) investigated the crystallinity and crystalline orientation within thin films of PDPPF-DTT. Figure 2 shows the resulting 2D scattering patterns along with the in-plane 40 (horizontal) and out-of-plane (vertical) scattering directions. Both the as cast and annealed films display a single broad semi crystalline alkyl stacking peak at q=3.2 nm⁻¹ (annealed) and g=3.6 nm⁻¹ (as-cast) corresponding to an average alkyl stacking distance (from one backbone to another across the alkyl side 45 chains) of 1.965(2) nm (annealed) and 1.73(2) nm (as-cast). The coherence length of alkyl stacking is 7.5(1) nm and 4(1) nm for annealed and as cast films, respectively. This sharpening of the scattering peaks upon annealing indicates that crystallinity increases dramatically upon annealing, producing larger and more 50 evenly spaced stacking through the film. A second broad peak, corresponding to the π -stacking direction, is found at q=1.56 nm⁻¹ (annealed) and 1.49 nm⁻¹ (as cast), corresponding to 0.40 nm and 0.43 nm respectively. The coherence length of stacking in the pi direction (out-of-plane) is 1.3 nm (annealed) and 1.0 nm (as cast) 55 indicating that this stacking is largely amorphous (only 2-3 repeat units per coherence length).



60 Figure 2. 2D scattering patterms of (a) as cast and (b) 250°C annealed thin films of PDPPF-DTT. For clarity, we also show sector plots in the (c) horizontal, in-plane direction and (d) vertical, out-of-plane direction.

Interestingly, the stacking observed for the as-cast film is largely face-on, with a herman's orientation order parameters 44 (which runs from perfectly face-on at -0.5 to perfectly edge-on at 1.0) of -0.01 +/- 0.01 for the annealed sample, indicating no preferred 5 orientation, and -0.15 for the as-cast sample, indicating a preference for face-on packing. In order to support GIWAXS data, we also investigated conventional XRD measurement. PDPPF-DTT spin coated on Si/SiO₂ substrate and thin film annealed at 250 °C showed a strong primary peak at 4.63°, which 10 corresponds to a d spacing of 19.1 Å as shown in Figure 3a. The observed interlayer spacing distance for PDPPF-DTT polymer is in the similar range with respect to earlier reported thiophene flanked diketopyrrolopyrrole with dithienothiophene (PDTTDPP- d-spacing of 20.3 Å) and selenophene flanked 15 diketopyrrolopyrrole with dithienothiophene (PSeDPPDTT- dspacing of 19.22 Å) copolymers.^{38, 40} An illustrative lamellar structure of PDPPF-DTT in the thin film form for getting clear understanding of interlayer spacing and π - π stacking is represented (see Figure 3b). GIWAXS data is also supported with 20 additional 2-D XRD measurements and the primary (100) and secondary (010) diffraction peaks observed from normal and parallel incident 2-D XRD measurements are attributed to interlayer spacing and π - π stacking distance respectively (see Figure 3c and 3d). During 2D XRD measurement, the 25 diffractogram exhibits a primary diffraction peak (100) at 2θ = 4.72° ($d = \sim 18.69$ Å) when the incident X-ray is normal to the polymer flakes whereas in parallel mode, the diffraction peak

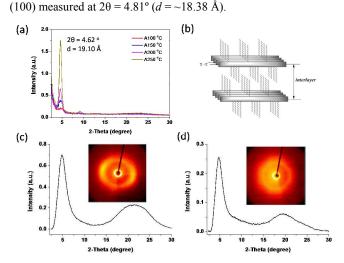


Figure 3. (a) XRD data obtained from spin-coated **PDPPF-DTT** thin films (~35 nm) on OTS modified SiO₂/Si substrates annealed at different temperatures (b) graphical lamellar structures of **PDPPF-DTT** in the thin film (c) 2-D XRD pattern intensity graphs (2-D XRD images in inset) 35 obtained with the incident X-ray parallel and (d) perpendicular to the thin film stack **PDPPF-DTT** copolymer.

The observed interspacing values obtained from conventional wide-angle XRD measurements are in a well agreement with 2D- $_{40}$ XRD measurements and found to be in the range of 18.38 to 19.1 Å. The broad featureless secondary diffraction peak suggests that all the polymer backbones are not aligned normal to the substrate. The broad peak from $2\theta=16.50\ ^{\circ}$ to $25.50\ ^{\circ}$ probably reflects

from both the π - π stacking distance of the crystalline domains and 45 the short range order of the amorphous region in the polymer thin films. The distance calculated from the broad peak maxima at 20 = 19.90° and 2θ = 21.43° in normal and parallel modes are d = \sim 4.45 Å and $d = \sim$ 4.14 Å respectively. The differences is stacking distances and limited enhancement in diffraction pattern in 50 parallel and perpendicular conditions of PDPPF-DTT suggests that the polymer chain in thin films may have a mixed edge on, face on and tilted orientations. Such kind of molecular organization was also observed for other furan flanked DPP polymer PDBFBT.³⁶ Despite of mixed orientations, PDBFBT 55 polymer exhibited high charge carrier mobility of 1.54 cm²/Vs in OFET devices. ³⁶ The electrical properties of **PDPPF-DTT** as an active channel semiconductor in OFET devices were evaluated using a bottom-gate, top-contact geometry. Heavily n-doped silicon wafer with a layer of ~200 nm SiO₂ on the surface was 60 used as the substrate. The SiO₂ functions as the gate insulator and the doped Si as the gate. The active polymer thin film (~40 nm) was spin coated on top of an octadecyltrichlorosilane (OTS) modified SiO₂ surface using a PDPPF-DTT solution in chloroform (7 mg/mL) at 1000 rpm for 60 seconds. The polymer 65 thin films were annealed at 100 °C, 150 °C, 200 °C and 250 °C respectively for 20 min on a hot plate in nitrogen atmosphere. On top of PDPPF-DTT thin film, gold was deposited as source and drain electrode via shadow masking method. The schematic of OFET device is shown in Figure 4a. OFET devices exhibit 70 typical p-channel electrical characteristics (Figure 4b and 4d). The hole mobility was calculated from the saturation regime of transfer curve.

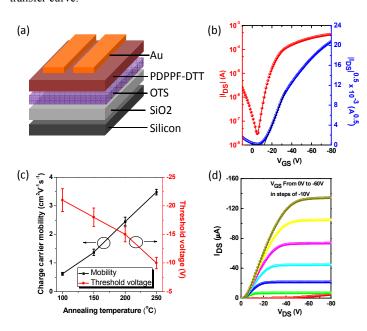


Figure. 4 (a) The schematic OFET device geometry used in this study and (b) the transfer characteristics of PDPPF-DTT OFET devices preannealed at 250°C. (c) Charge carrier mobilities and threshold voltage as a function of annealing temperatures. (d) The output characteristics of PDPPF-DTT OFET devices pre-annealed at 250°C. Device dimensions:
 channel length = 100 μm; channel width = 1 mm. All devices are measured in a dry N₂ filled glove box

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Table 1. OFET device performance of PDPPF-DTT thin films annealed at 100, 150, 200 and 250 °C on OTS treated n+-Si/SiO₂ substrates using bottom-gate, top-contact (BGTC) devices.

	TA	hole		
		$\mu[\text{cm}^2\text{V}^{-1}\text{s}^{-1}]$	$V_{T}[V]$	On/off
PDPPF-DTT	100	0.46-0.68	-21	10 ⁵
PDPPF-DTT	150	1.05-1.48	-18	10^{5}
PDPPF-DTT	200	2.03-2.60	-15	10^{5}
PDPPF-DTT	250	3.18-3.56	-10	10^{4}

5 The polymer thin film annealed at 100 °C exhibited hole mobility in the range of 0.46 to 0.68 cm²/Vs. Upon further enhancing the maximum to 1.48 cm²/Vs. Interestingly, when the annealing temperature is further increased to 200 °C, the hole mobility was improved further up to 2.60 cm²/Vs. The polymer annealed at 250 ¹⁰ °C showed the highest hole mobility value of 3.56 cm²/Vs (see Figure 4c and Table 1). The transfer and output characteristics of 250 °C annealed PDPPF-DTT based devices are shown in Figure 4b and 4d respectively. It should be noted that ambipolar behavior with weak electron transport could be observed due to 15 its low band gap nature. The on/off ratio for all of the devices was around 10⁵ whereas the threshold voltage observed decreased from -21 V to -10 V when increasing the annealing temperature due to reduced charge traps. According to our knowledge, the reported hole mobility of 3.56 cm²/Vs for **PDPPF-DTT** is one of 20 the highest hole mobility values based on the furan flanked DPP based copolymers using straightforward simple geometry. This value is also one of the highest values among dithienothiophenebased copolymers. A fused aromatic moiety such as DPP and DTT in the backbones makes this particular polymer a very 25 planar system which enhances the orbital overlapping for better charge transport. In addition to that a conjugated alternating D-A polymer offers the feasibility of creating a ground-state partial charge-transfer state and such weakly polarized state would assist for the effective charge transport. This clearly 30 demonstrates that prejudicially designed using easily accessible fused aromatic building block via appropriate manner can achieve such an impressive mobility. In order to study the effect of annealing temperature on the OFET performance, we also conducted morphological investigation of PDPPF-DTT thin film 35 using various preannealing temperature via atomic force microscopy (AFM). The AFM images reveals the dependence of the mobility values on the morphology of the polymer thin films related to the various annealing temperature (see Figure S5 in Supporting Information). From the AFM images of the polymer 40 thin films, it can be observed that the non-annealed polymer thin

film exhibits some sort of protrusion which can resembles "stripes" on to a continuous film. Such protrusions can be arises due to the morphological inhomogeneties and they can be 45 disappeared upon annealing. At the 250 °C annealed sample, the domain size increased to micrometer scale and covered entire film (RMS roughness = 2.21 nm). We strongly believe that an efficient charge transport in PDPPF-DTT semiconductor thin films annealed at 250 °C is due to interconnected network of 50 large domains. The compact crystalline domains in the thin films with an increasing annealing temperature is in a good agreement with the XRD results, this clearly demonstrate the enhancement in crystallinity of the thin films upon annealing from lower to higher temperature. Such a highly ordered morphology is 55 complimentary for the efficient charge transport trails between source and drain electrodes. A good planarity and the strong electron withdrawing and donating capabilities of highly fused aromatic DPP and DTT moiety enhances a strong intermolecular interaction which leads significant ordering and preferably 60 oriented molecular organization and thus enables efficient charge transport with a high mobility in PDPPF-DTT polymer based OFETs. In addition to that S...S interaction and enhancement in structural planarity endorses extensive intramolecular π conjugation and close intermolecular π - π stacking. π -Conjugated 65 dithienothiophene-based molecules self-organize into singlecrystal microribbons via attractive intermolecular S...S interactions by a simple solution process and noticeably high hole mobilities of up to 10.2 cm² /Vs has been achieved in organic single-crystal field-effect transistors. 45 However, by combining 70 dithienothiophene with furan substituted diketopyrrolopyrrole can achieve such an impressive 3.56 cm²/Vs mobility in polydipserse polymer based OFETs in comparison with monodisperse single crystal. These results clearly reveal that an appropriate fused aromatic donor-acceptor based molecular design could achieve an 75 impressive performance in p-channel OFETs using elegant synthesis and modest device geometry. Such polymer can be also highly potential class of materials for fabricating logic gate devices via nanostructuration approach⁴⁶ owing to their high mobility. A significant improvement in electrical performance for 80 p-type small molecule ⁴⁷as well as for ambipolar polymer ⁴⁸ was

successfully obtained by using such a stamp-assisted deposition approach where lithographically controlled wetting and micromolding in capillaries plays a major role.

Conclusions

- ⁵ In summary, we have successfully designed and synthesized a new solution processable polymer semiconductor **PDPPF-DTT** by combining a furan flanked diketopyrrolopyrrole and diehtienothiophene fused aromatic building blocks via Stille coupling. **PDPPF-DTT** exhibits wide UV-vis-NIR absorption
- 10 starting from 350 nm to 900 nm with a lower optical band gap of 1.37 eV. The calculated HOMO value of 5.36 eV for **PDPPF-DTT** makes it suitable candidate for stable *p*-channel OFET devices. Top contact bottom gate OFET devices based on **PDPPF-DTT** as an active channel semiconductor showed hole
- nobility as high as 3.56 cm²/Vs annealed at 250 °C. The measured hole mobility value observed in **PDPPF-DTT** polymer is one of the highest values among known furan flanked DPP based organic semiconductors. Such a high mobility value and elegant synthesis opens up many possibilities to use the fused
- 20 furan flanked DPP as a promising building block for synthesizing novel high performance conjugated polymers.

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Notes and references

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- †Electronic Supplementary Information (ESI) available: NMR data of starting monomers 2 and 4, DSC and TGA data of monomers and 55 PDPPF-DTT. See DOI: 10.1039/b000000x/

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